Dielectric anomalies due to grain boundary conduction in chemically substituted BiFeO3


Citation: Journal of Applied Physics 117, 114102 (2015); doi: 10.1063/1.4915110
View online: http://dx.doi.org/10.1063/1.4915110
View Table of Contents: http://scitation.aip.org/content/aip/journal/jap/117/11?ver=pdfcov
Published by the AIP Publishing

Articles you may be interested in

Phase transition and enhanced magneto-dielectric response in BiFeO3-DyMnO3 multiferroics

Evidence of improved ferroelectric phase stabilization in Nd and Sc co-substituted BiFeO3

Effect of Pr- and Nd- doping on structural, dielectric, and magnetic properties of multiferroic Bi0.8La0.2Fe0.9Mn0.1O3
J. Appl. Phys. 115, 134102 (2014); 10.1063/1.4870454

Effect of coalesce doping of Nd and La on structure, dielectric, and magnetic properties of BiFeO 3

Unambiguous evidence for magnetoelectric coupling of multiferroic origin in 0.73 BiFeO 3 – 0.27 PbTiO 3
Dielectric anomalies due to grain boundary conduction in chemically substituted BiFeO$_3$

Shalini Kumari,$^1$ N. Ortega,$^1$ A. Kumar,$^2$ S. P. Pavunnu,$^1$ J. W. Hubbard,$^3$ C. Rinaldi,$^3$
G. Srinivasan,$^4$ J. F. Scott,$^5$ and Ram S. Katiyar$^1$

$^1$Department of Physics and Institute for Functional Nanomaterials, University of Puerto Rico, San Juan, Puerto Rico 00931-3334, USA
$^2$CSIR-National Physical Laboratory, New Delhi, India
$^3$Department of Chemical Engineering and Institute for Functional Nanomaterials, University of Puerto Rico, Mayaguez, Puerto Rico 00681, USA
$^4$Physics Department, Oakland University, Rochester, Michigan 48309-4401, USA
$^5$Cavendish Laboratory, Department of Physics, Cambridge University, Cambridge CB3 0HE, United Kingdom

(Received 7 January 2015; accepted 4 March 2015; published online 17 March 2015)

We describe systematic studies on Nd and Mn co-doped BiFeO$_3$, i.e., (Bi$_{0.95}$Nd$_{0.05}$)(Fe$_{0.97}$Mn$_{0.03}$)O$_3$ (BNFM) polycrystalline electroceramics. Raman spectra and X-ray diffraction patterns revealed the formation of rhombohedral crystal structure at room temperature, and ruled out structural changes in BiFeO$_3$ (BFO) after low percentage chemical substitution. Strong dielectric dispersion and a sharp anomaly around 620 K observed near the Néel temperature ($T_N \sim 643$ K) of BFO support strong magneto-dielectric coupling, verified by the exothermic peak in differential thermal data. Impedance spectroscopy disclosed the appearance of grain boundary contributions in the dielectric data in the region, and their disappearance just near the Néel temperature suggests magnetically active grain boundaries. The resistive grain boundary components of the BNFM are mainly responsible for magneto-dielectric coupling. Capacitive grain boundaries are not observed in the modulus spectra and the dielectric behavior deviates from the ideal Debye-type. The ac conduction studies illustrate short-range order with ionic translations assisted by both large and small polaron hopping. Magnetic studies indicate that the weak antiferromagnetic phase of BNFM ceramics is dominated by a strong paramagnetic response (unsaturated magnetization even at applied magnetic field of 7 T). The bulk BNFM sample shows a good in-plane magnetoelastic coupling (ME) coefficient. © 2015 AIP Publishing LLC.

I. INTRODUCTION

Multiferroic magnetoelastic (MF-ME) materials have been widely and extensively studied due to their unique natural properties. Single-phase multiferroic materials have attracted much attention in the last decade; these systems possess both ferroelectric and ferromagnetic properties simultaneously, in which application of an electric field or magnetic field can alter the magnetization or electric polarization, respectively. Room temperature single-phase multiferroic materials are rare in nature; recent discoveries have revealed several systems having active polarization even above room temperature; however, the small magnitude of polarization and cross coupling has serious limitations for practical devices. Different origins of ferroelectricity have been explored, such as charge ordering, magnetically induced ferroelectricity, lone-pair electron effects, octahedral distortion, strain mediation, geometrical frustration, etc., but in general, ferroelectricity results from relative shifts of negative and positive ions that induce surface charges. The MF-ME materials have a strong research interest due to both the rich fundamental physics and the number of potential multi-functional applications in modern technologies.

In general, magnetoelastic multiferroic single phase materials can be divided into three main groups: (i) Perovskite oxides (Relaxor Pb-family, bismuth compounds, rare earth (RE) manganites, mixed perovskite solid solutions), (ii) other oxides (RE$m_n$O$_5$ family), and (iii) non oxides (phosphates, boracites, fluoride family chalcogenides, and delafossites).

Many of the compounds in the above-mentioned groups have drawbacks: they are multiferroic only at low temperature; they have very low ferroelectric and/or ferromagnetic response; and exhibit low values of magnetoelastic coupling constant for practical applications. BFO has both ferroelectric and antiferromagnetic properties at room temperature, i.e., G-type antiferromagnetic phase transition ($T_N = 643$ K) and ferroelectric-paraelectric phase transition ($T_C = 1143$ K). A major drawback is conducting grain boundaries and domain walls, but ironically the latter permits enriched functionalities based on domain walls.

In BFO, ferroelectric and transport properties are also hindered by its high leakage current, which arises due to the presence of defects, nonstoichiometry, and low resistivity. For practical multifunctional applications of this material, it is essential to improve its multiferroic properties with low leakage currents. This can be achieved by introducing suitable dopant ions at A and B sites in this material. A or B sites substitution in BFO can lead to reduction in leakage current, increase in resistivity, and enhancement in the ferroelectric and ferromagnetic properties. Hence, there is a lot of research going on in the synthesis of suitably doped BFO. For
example, Yu et al.\textsuperscript{13} synthesized Bi$_{0.85}$La$_{0.15}$Fe$_{0.97}$V$_{0.03}$O$_3$ and found reduction in the leakage current density by about one or two orders of magnitude in comparison with singly doped-BFO (Bi$_{0.85}$La$_{0.15}$Fe$_2$O$_5$ and BiFe$_{0.97}$V$_{0.03}$O$_3$). Hu et al.\textsuperscript{14} reported that Bi$_{0.85}$Nd$_{0.15}$Fe$_{0.98}$Mn$_{0.02}$O$_3$ ceramics exhibited a larger dielectric constant (165), larger remanent polarization value (31 $\mu$C/cm$^2$), and a considerable improvement in magnetic properties compared to pure BFO. Kawae et al.\textsuperscript{15} studied (Bi$_{1.0}$Nd$_{0.05}$)(Fe$_{0.97}$Mn$_{0.03}$)O$_3$ thin films and found that these films showed lower leakage current density than that of BFO, Bi$_{1-x}$Nd$_x$Fe$_3$O$_{12}$ (BNF), and BiFe$_{1-x}$Mn$_x$O$_3$ (BFM) films in a wide range of electric fields. Kawae et al.\textsuperscript{16} have studied the leakage current density of Bi$_{1-x}$Nd$_x$Fe$_3$Mn$_x$O$_3$ ($x = 0.07$ and $y = 0.07$) thin films and achieved the lowest leakage current in the films with the composition of $x = 0.05$ and $y = 0.03$. They also concluded that small amount of Mn substitution is very effective in reducing the leakage current, whereas excess substitution leads to an increase in leakage current.

From the literature, it can be concluded that co-substituted BFO show better electrical and magnetic behavior than single phase BFO along with reduced leakage current. Thus, we have been motivated for the co-substitution of Nd$^{3+}$ in A sites and Mn$^{4+}$ in B sites of BFO to achieve enhanced magnetic, electrical, and magnetoelectric properties with reduced leakage current. Nd helps in suppressing the formation of secondary phases, reducing the leakage current and improving ferroelectric or magnetic properties, whereas substitution by transition metal ions (Mn$^{4+}$) reduces the fluctuation of the Fe valence and oxygen vacancies, which is an important factor to reduce the leakage current.\textsuperscript{15-21} Based on the literature, the present doping concentration of Nd and Mn in BFO has been chosen for our studies as this composition shows lowest leakage current with enhanced electrical properties among all the substitutional compositions.\textsuperscript{16}

In this work, the main aim is to study the structural, dielectric, impedance, magnetic, and magnetoelectric properties of BNFM system. Also, we report the dielectric and impedance behavior of BNFM near the magnetic phase transition temperature and ME coupling at room temperature. We show unambiguously that resistive grain boundary conduction is responsible for the large magneto-dielectric anomaly near the Néel temperature.

### II. EXPERIMENTAL DETAILS

The conventional solid-state reaction route method with high purity ingredients (99.99%) Bi$_2$O$_3$, Nd$_2$O$_3$, Fe$_2$O$_3$, and Mn$_2$O$_3$ (Alfa Aesar) was employed to prepare (Bi$_{0.95}$Nd$_{0.05}$)(Fe$_{0.97}$Mn$_{0.03}$)O$_3$ (BNFM) samples. These powders were carefully weighted in stoichiometric proportion while 15% excess Bi$_2$O$_3$ was added to the mixture to compensate Bi volatility during the synthesis of material. Polyvinyl alcohol solution (1%) was added into the dried powders as a binder then pressed using a hydrostatic press (3.9 $\times$ $10^4$Pa) into pellets of 13 mm diameter. These pellets were sintered at 860 °C for 6 h. All heat treatments were performed in air. The flat surface of the sintered pellets was polished with fine emery paper, and then top and bottom electrodes were made by coating high purity silver paint followed by firing at 200 °C in air for better conduction and adhesion. Crystalline phases of the sintered pellets were identified via X-ray diffractometry (Rigaku Ultima III) using CuK$_\alpha$ radiation with wavelength of $\lambda = 1.5405$ Å. Simulation of the crystal structure of BNFM samples based on the measured x-ray diffraction (XRD) data was carried out using refinement software (Fullprof). Scanning electron microscopy (SEM) images were recorded using a JEOL JSM-6480LV system operated with an accelerating voltage of 20 kV. The composition of fabricated ceramics was confirmed by X-ray fluorescence spectroscopy (XRF) and high-resolution X-ray photoemission spectroscopy (XPS). Raman measurements of BNFM samples were carried out in the backscattering geometry using the 514.5 nm line from an Ar ion laser in the temperature range from 80 K to 700 K. The scattered light was dispersed by a T64000 spectrometer and collected with a charge-coupled device (CCD) detector. Calorimetric properties were measured using differential scanning calorimetry (DSC). Equilibrium magnetization curves at various temperatures were acquired using a superconducting quantum interference device (SQUID) magnetometer from Quantum Design (MPMS-XL7). Dielectric measurements (capacitance and tangent loss) were carried out in the temperature range of 100 K to 670 K for frequencies between 100 Hz and 1 MHz using a programmable temperature controller (MMR K-20) and an impedance analyzer (HP 4294A). The magneto-electric voltage coefficient for BNFM ceramics poled for 12 h in a constant electric field was determined by dynamic methods as a function of bias field H at ac field $H_{ac} = 4500$ Oe and frequency 1 kHz by measuring the voltage across the sample utilizing a lock-in-amplifier.

### III. RESULTS AND DISCUSSION

#### A. XRD and Rietveld refinement

To investigate the structure and lattice characteristics of Nd and Mn co-doped BFO ceramics, Rietveld refinement of experimental XRD pattern of BNFM was carried out using Fullprof suite software package.\textsuperscript{22,23} Figure 1(a) shows the observed and calculated diffraction patterns of BNFM ceramics at room temperature. Experimental XRD of BNFM shows a very low intense peak at $\sim 20 = 28^\circ$ (marked as *) assigned to the Bi$_3$Fe$_2$O$_9$ phase, which can be due to excessive Bi used for compensating volatilization during material synthesis.\textsuperscript{24} the Bi$_3$Fe$_2$O$_9$ is about 2% compared to the intense peak in BNFM XRD spectra. In these XRD patterns, no extra splitting can be observed in characteristic rhombohedral peaks; thus, it can be concluded that there is no phase transition occurring from rhombohedral to tetragonal or other phases with co-doping of Nd and Mn in A and B sites of BFO.\textsuperscript{25} Most of the diffraction peaks in this XRD pattern of BNFM shift slightly towards higher angle compared to those of BFO due to slight lattice compression by chemical doping of Nd and Mn at A and B sites. The Rietveld refinement of BNFM ceramics has been carried out by considering the rhombohedrally distorted perovskite structure with space group R3c, initial lattice parameters
and atomic positions for the simulation were taken from those reported elsewhere. The shape of peaks was refined by Pseudo-Voigt function and scale factor, zero shift, specimen displacement, background, transparency, lattice parameters, FWHM, shape parameters, atomic positions, preferred orientation, and anisotropic temperature parameters were varied during refinement process. The diffractometer parameters used for data collection, the crystal structure parameters derived from simulation, and reliability factors are all listed in Table I. The structural parameters obtained from refinement (Table I) match well with the reported values for BFO and doped-BFO. The decrease in lattice parameters and unit cell volume observed in BNFM in comparison with pure BFO is due to the fact that the effective ionic radii of Nd$^{3+}$ (0.983Å)/Mn$^{4+}$ (0.530Å) are lower than those of Bi$^{3+}$ (1.03Å)/Fe$^{3+}$ (0.645Å) in A and B sites. The density of the BNFM ceramics was measured using Archimedes principle and it was found to be 7.32 g/cm$^3$. This value is about 92% of the theoretical BFO density, and is close to the value 7.418 g/cm$^3$ obtained from XRD refinement analysis given in Table I.
The reliability factors (Table I) match well with reported values for BFO and doped BFO.\textsuperscript{21,26} All prominent Bragg peaks were successfully indexed using the JCPDS x-ray diffraction file of pure BFO [JCDPS #821254]. Table II summarizes the atomic site occupancy (Wyckoff) parameters, in the unit cell of BFO there are three atoms occupying the following Wyckoff positions 6a (Bi\textsuperscript{3+} and Fe\textsuperscript{3+}) and 18b (O\textsuperscript{2−}), in BNFM, the 6a site can be occupied by Bi\textsuperscript{3+}/Nd\textsuperscript{3+} or Fe\textsuperscript{3+}/Mn\textsuperscript{4+}, x, y, z values obtained by refinement are in agreement with the values reported earlier.\textsuperscript{21,27}

Figure 1(b) shows a three-dimensional sketch of the refined BNFM unit cell with rhombohedral structure and R3c spacegroup in hexagonal setting, matching well with earlier reports on BFO and doped BFO.\textsuperscript{26,31,32} The analysis of the BNFM unit cell revealed that the Bi and Fe atoms are coordinated to six O atoms in an octahedral configuration, forming the distorted octahedral BiO\textsubscript{6} and octahedral FeO\textsubscript{6}, where Bi and Fe cations are at the centre of the octahedra.\textsuperscript{31,33,34} The observed distance between Bi/Nd and Fe/Mn with O is given in Table II. The longest bond of length 2.4914 Å is found between Bi/Nd and O and the shortest (1.9277 Å) one between Fe/Mn and O. Figure 1(c) shows a well defined electron density distribution along (x,y,0), (0,y,z), and (x,0,z) in the BNFM unit cell.

### TABLE I. Diffractometer data collection parameters, crystal structure parameters, and reliability factors of BNFM samples obtained from Rietveld refinement at room temperature.

<table>
<thead>
<tr>
<th>Molecular formula</th>
<th>(\text{Bi}<em>{0.93}\text{Nd}</em>{0.07}\text{Fe}<em>{0.97}\text{Mn}</em>{0.03}\text{O}_3)</th>
</tr>
</thead>
<tbody>
<tr>
<td>Diffractometer</td>
<td>Rigaku Ultima III</td>
</tr>
<tr>
<td>CuK(_\alpha)</td>
<td>(\lambda = 1.5405 \text{ Å})</td>
</tr>
<tr>
<td>Scan mode</td>
<td>0–20°</td>
</tr>
<tr>
<td>2θ range</td>
<td>20–80°</td>
</tr>
<tr>
<td>Scan width-scan</td>
<td>0.01, 1° min(^{-1})</td>
</tr>
<tr>
<td>Speed</td>
<td></td>
</tr>
<tr>
<td>Crystal Symmetry</td>
<td>Rhombohedral</td>
</tr>
<tr>
<td>Space group</td>
<td>R3c</td>
</tr>
<tr>
<td>Unit cell parameters</td>
<td>(a = b = 5.7778 \text{ Å} ; c = 13.8363 \text{ Å})</td>
</tr>
<tr>
<td>Volume</td>
<td>372.8031 Å(^3)</td>
</tr>
<tr>
<td>Density</td>
<td>7.418 g/cm(^3)</td>
</tr>
<tr>
<td>No of least-squares</td>
<td>68(30 anisotropic thermal parameters varied)</td>
</tr>
<tr>
<td>Coordination</td>
<td>6</td>
</tr>
<tr>
<td>Profile function</td>
<td>Pseudo-Voigt</td>
</tr>
<tr>
<td>FWHM parameters (U, V and W)</td>
<td>0.50747, −0.32487, 0.09190</td>
</tr>
<tr>
<td>Preferred orientation parameters</td>
<td>0.0, 0.0</td>
</tr>
<tr>
<td>Pattern residual ((R_p))</td>
<td>18.2</td>
</tr>
<tr>
<td>Weighted pattern residual ((R_{wp}))</td>
<td>24.2</td>
</tr>
<tr>
<td>Expected residual ((R_{exp}))</td>
<td>4.30</td>
</tr>
<tr>
<td>Bragg factor ((R_B))</td>
<td>12.6</td>
</tr>
<tr>
<td>Structural factor ((R_F))</td>
<td>6.59</td>
</tr>
</tbody>
</table>

### B. Surface morphology

The scanning electron microscopy (SEM) micrographs illustrate the grain growth, voids, boundaries, and surface morphology of BNFM samples as can be seen in Figures 2(a) and 2(b). Figure 2(a) shows that the BNFM samples have a polycrystalline nature: larger grains with varying grain size from 5 to 10 μm, densely packed with almost no enclosed pores in the sintered ceramics, without macroscopic defects such as cracks or micro-cracks. Magnified morphology of BNFM sample (Figure 2(b)) shows a clear granular structure with a maximum grain size of ~10 μm, with a marked grain boundary region, and few pores among the grains. The wide distribution of the grain size observed in the SEM image can be due to relatively higher temperature and longer duration involved in sintering process. Formation of wider/bigger grains (from smaller grains) with grain boundary junctions takes place during this high temperature process.\textsuperscript{35–37} On the other hand, dense morphology, large grains, and surrounded grain boundaries favor the grain boundary stimulated magneto-dielectric response near the Néel temperature, as evidenced and discussed in the section of electrical properties.\textsuperscript{37}

### C. X-ray photoemission spectroscopy

The valence state of Fe ions in BNFM ceramics was examined by high-resolution X-ray photoemission spectroscopy (XPS). Figure 3(a) shows the full XPS spectra of BNFM ceramics with photoelectron characteristic peaks Bi 4f\(_{7/2}\) (157.71 eV), Bi 4f\(_{5/2}\) (162.99 eV), Nd 3d\(_{5/2}\) (981.32 eV), Nd 3d\(_{3/2}\) (1004.00 eV), Fe 2p\(_{3/2}\) (709.35 eV), Fe 2p\(_{1/2}\) (722.92 eV), Mn 2p\(_{3/2}\) (640.66 eV), Mn 2p\(_{1/2}\) (652.45 eV), O 1s (528.35 eV), respectively. Systematic shifts of the XPS spectra were corrected using the 1s line (284.6 eV) of carbon. It was observed that photoelectron peaks for almost all elements shifted to slightly higher binding energy, which may be due to decrease of electron charge density on the atoms.\textsuperscript{38} From the inset of Figure 3(b), it was observed that Fe 2p doublet consists of Fe 2p\(_{3/2}\) and Fe 2p\(_{1/2}\) peaks, the difference in binding energy between 2p\(_{3/2}\) and 2p\(_{1/2}\) for Fe ions is around 13.6 eV and matches well with the standard value. We have observed one weak peak at 717 eV which is shake-up satellite peak of Fe 2p\(_{3/2}\) may be originated by the configuration interaction due to relaxation of valence electrons.\textsuperscript{39,40} Figure 3(b) shows the XPS experimental spectrum (open circles), fitted data (red solid line), and Shirley-type background (orange dashed line) for Fe 2p\(_{3/2}\) in BNFM ceramics. In our case, the measured Fe 2p\(_{3/2}\) peak was deconvoluted into two peaks, which suggest the coexistence of Fe\textsuperscript{2+} and Fe\textsuperscript{3+} states (Fig. 3(b)). From the percentage area under the peaks shifted to slightly higher binding energy, which may be due to decrease of electron charge density on the atoms.\textsuperscript{38} From the inset of Figure 3(b), it was observed that Fe 2p doublet consists of Fe 2p\(_{3/2}\) and Fe 2p\(_{1/2}\) peaks, the difference in binding energy between 2p\(_{3/2}\) and 2p\(_{1/2}\) for Fe ions is around 13.6 eV and matches well with the standard value. We have observed one weak peak at 717 eV which is shake-up satellite peak of Fe 2p\(_{3/2}\) may be originated by the configuration interaction due to relaxation of valence electrons.\textsuperscript{39,40} Figure 3(b) shows the XPS experimental spectrum (open circles), fitted data (red solid line), and Shirley-type background (orange dashed line) for Fe 2p\(_{3/2}\) in BNFM ceramics. In our case, the measured Fe 2p\(_{3/2}\) peak was deconvoluted into two peaks, which suggest the coexistence of Fe\textsuperscript{2+} and Fe\textsuperscript{3+} states (Fig. 3(b)). From the percentage area under the Fe 2p\(_{3/2}\) peak obtained from fitting, the concentration ratio of Fe\textsuperscript{3+} and Fe\textsuperscript{2+} in BNFM ceramics was found to be 70:30,
which indicates that the presence of Fe$^{2+}$ ions is less than Fe$^{3+}$. Similar to BFO, the existence of Fe$^{2+}$ is inevitable due to the sintering process in air, which can introduce defects in the form of oxygen vacancies and it could also affect the dielectric properties of BNFM ceramics.41–43

D. Raman spectroscopy

Raman spectroscopy is a sensitive technique to investigate changes in lattice vibrations with dopings at different sites of the unit cell. Figure 4(a) presents the unpolarized Raman spectra as a function of temperature for BNFM ceramic. The open symbols correspond to the experimental data and the solid lines the fitted Raman spectra. Group theory predicts that rhombohedral BFO with R3c structure should have 13 Raman active phonons: $\Gamma_{\text{Raman}} = 4A_1 + 9E$.44,45 we have analyzed Raman data taking in to account that the XRD Rietveld analysis revealed that BNFM has similar crystal structure and space group as BFO. In this work, we have observed 9 Raman active modes ($3A_1 + 6E$) for BNFM ceramic at 83 K and room temperature (RT); however at RT the E modes above 250 cm$^{-1}$ are weak. A few modes are not observable or faint in Raman spectra which may be due to dielectric leakage in polycrystalline sample. The temperature variation of the modes observed for the bulk Bi$_{0.95}$Nd$_{0.05}$Fe$_{0.97}$Mn$_{0.03}$O$_3$ (BNFM) in this study, the observed modes for bulk BFO by other authors at RT and 93 K (Refs. 46, 47, and 25) and reported modes for Bi$_{0.825}$Nd$_{0.175}$FeO$_3$ (Ref. 26) are included in Table III. From this table, we can observe that a similar number of modes were reported for BFO at 93 K and at RT by Kothari et al. and Rout et al.46 It was noted that the Raman spectra of BNFM at low temperature (83 K) and RT (Figure 4(a) and Table III) are very similar, supporting the idea that the rhombohedral (R3c space group) structure is retained in Nd, Mn co-doped BFO ceramics; similar results were obtained by Haumont et al.48 for BFO single-crystals. Singh et al.49 have reported $A_1$ and low frequency E modes corresponding to Bi-O bonds, whereas higher frequency E modes are related to Fe-O bonds. Comparing the frequency values obtained for BNFM and BFO Raman modes (Table III), it is clear that these modes shifted to higher frequencies when BFO was co-doped with Nd and Mn; this result can be due to difference in the atomic mass of Bi (208.98 g) and Fe (55.84 g) when they are replaced by Nd (144.24 g) and Mn (54.94 g). From Figure 4(a), we can observe the following features in Raman spectra with increase of temperature: (i) reduction in the peak intensity, (ii) lower frequency values (see dotted line in Figure 4(a)), (iii) marked widening of the peaks, and (iv) pronounced decrease in the intensity of Raman modes (this effect is more pronounced in high wavenumber peaks (>400 cm$^{-1}$), which disappears near $T_N \sim 620$ K). Similar observations were reported by other researchers in bulk and single-crystal
The observed vibrational modes in BNFM were fitted with the spectral damped harmonic oscillator (DHO) model. The observed mode below $T_N$ has a dielectric maximum ($\varepsilon_r / C_0$) before $T_N$, whereas $3A_1$ mode disappeared at $\sim 433$ K, before $T_N$. The $1A_1$, and $2A_1$ modes gradually decrease and became almost constant around $T_N$; however, less wavenumber variation was observed for $1E$ mode below $T_N$ (see dashed lines and arrows in Figure 4(a)).

Similar anomalies were observed in the FWHM vs temperature curve for the same modes (Figure 4(b)-lower), however, changes were weak. Similar results were reported by Haumont et al. and Rout et al. in single-crystal and bulk BFO, respectively. The AFM-PM transition in BFO is a purely magnetic phase transition, in which structural changes are not present, but it was noted that the error in the Raman fit increased considerably in this region; this can be due to subtle structural rearrangement at the local level. Similar phonon anomalies were observed near the magnetic phase transition in other ferromagnetic oxide materials but less pronounced compared with BFO.

E. Dielectric spectroscopy

Figures 5(a) and 5(b) present the temperature dependent dielectric constant ($\varepsilon_r$) and tangent loss ($\tan \delta$) (inset) of the BNFM ceramics in the frequency range from 500 Hz to 1 MHz during heating and cooling process, respectively. A dielectric anomaly was observed in the vicinity of the antiferromagnetic–paramagnetic transition of BFO at $T_N$ (see green area in Figures 5(a) and 5(b)), it was observed that it has a dielectric maximum ($T_m$) at $\sim 620$ K over large frequency range in the vicinity of $T_N$. Scott et al. reported that magnetoelastic coupling can be measured indirectly by...
TABLE III. Raman wavenumbers obtained for the BNFM ceramic samples at different temperatures.

<table>
<thead>
<tr>
<th>Raman modes (cm⁻¹)</th>
<th>Bi₀.₉₅Nd₀.₀₅Fe₀.₇₅Mn₀.₀₃O₃ (present study)</th>
<th>BFO (from literature)</th>
<th>Bi₀.₆₂₅Nd₀.₁₇₅FeO₃</th>
</tr>
</thead>
<tbody>
<tr>
<td></td>
<td>83 K</td>
<td>RT</td>
<td>433 K</td>
</tr>
<tr>
<td>1A₁⁻</td>
<td>145</td>
<td>139</td>
<td>132</td>
</tr>
<tr>
<td>2A₁⁻</td>
<td>175</td>
<td>172</td>
<td>166</td>
</tr>
<tr>
<td>3A₁⁻</td>
<td>228</td>
<td>231</td>
<td>...</td>
</tr>
<tr>
<td>4A₁⁻</td>
<td>...</td>
<td>...</td>
<td>...</td>
</tr>
<tr>
<td>1E</td>
<td>76</td>
<td>75</td>
<td>72</td>
</tr>
<tr>
<td>2E</td>
<td>...</td>
<td>...</td>
<td>...</td>
</tr>
<tr>
<td>3E</td>
<td>264</td>
<td>277</td>
<td>...</td>
</tr>
<tr>
<td>4E</td>
<td>284</td>
<td>335</td>
<td>...</td>
</tr>
<tr>
<td>5E</td>
<td>...</td>
<td>...</td>
<td>...</td>
</tr>
<tr>
<td>6E</td>
<td>...</td>
<td>...</td>
<td>...</td>
</tr>
<tr>
<td>7E</td>
<td>482</td>
<td>480</td>
<td>...</td>
</tr>
<tr>
<td>8E</td>
<td>524</td>
<td>529</td>
<td>...</td>
</tr>
<tr>
<td>9E</td>
<td>624</td>
<td>628</td>
<td>620</td>
</tr>
</tbody>
</table>

simply recording changes in either the magnetization near, say, a ferroelectric transition temperature or the dielectric constant near a magnetic transition temperature. In the present study, we found a change in dielectric properties around Neel temperature which suggest the existence of magneto-electric coupling. This dielectric maxima around \( T_N \) in magneto-electric materials was attributed to the effect of vanishing magnetic ordering on electric order.⁵⁵⁻⁶⁷ Wang et al.⁶⁸ found a local minimum of rhombohedral angle, which was associated with the displacement in positions of Bi\(^{3+}\) and Fe\(^{3+}\) as temperature comes close to \( T_N \). A similar type of anomaly around 620 K has been observed for temperature dependent \( \tan \delta \) and thermal data (explained in Section III F) of this sample, which is shown in the insets of Figures 5(a) and 5(b). With the rise of temperature, further increment in \( \tan \delta \) has been observed above \( T_N \); similar behavior in \( \tan \delta \) has been observed by other researches, e.g., Pandit et al.⁵⁹ observed an increase of \( \tan \delta \) until \(~40\) at 500 Hz for Bi\(_{1.83}\)Nd\(_{0.07}\)La\(_{0.1}\)Fe\(_{0.93}\)O\(_3\) ceramics near the Neel temperature; Uniyal et al.⁶⁰ found \( \tan \delta \) as \(~10\) at 100 kHz for Bi\(_{1.95}\)Eu\(_{0.05}\)Fe\(_{0.95}\)O\(_3\) at 400°C and Biswal et al.⁶¹ observed \( \tan \delta \) between 80 and 100 at 10 kHz for Ni doped BFO ceramics for different compositions at about 400°C. This behavior can be due to contribution of space charge polarization, which arises because of oxygen ion vacancies at high temperature.⁵⁵ Another reason is the presence of the Fe ion, which is a transition element, because of that ionic conduction (Fe\(^{3+}\) to Fe\(^{2+}\)) is increasing inside the sample, resulting in an increase in \( \tan \delta \) at higher temperatures. The abrupt increase in \( \tan \delta \) during heating process compared with the cooling process may arise due to thermal activation of space charge polarization during heating that is higher than in the cooling process.

F. Thermal analysis

Differential scanning calorimetric (DSC) measurement was carried out on BNFM samples and the results are shown in Figure 5(c). The heat flow curve indicates an endothermic peak around 620 K which may be related with magneto-dielectric coupling and sharp change in dielectric maxima in the vicinity of \( T_N \); however, a broad exothermic peak related to the magnetic phase transition can also be seen around 638–643 K (inset of Figure 5(b)). Similar results have been obtained by other authors for pure and doped-BFO.⁵⁵,⁶²–⁶⁴ For example, Varshney et al.⁶² observed the energy change around 370°C (643 K) in the DSC plot and correlated it to magnetic phase transition from antiferromagnetic to paramagnetic. Wei et al.⁶³ observed endothermic peak around 400°C corresponding to the magnetic \( (T_N) \) phase transition. Perejon et al.⁶⁴ also reported a transition around 370°C in DSC plot corresponding to the Neel temperature, \( T_N \), for the phase transition from the antiferromagnetic to paramagnetic.

The ferroelectric-paraelectric transition of BNFM which is expected at higher temperature (above 1000 K) could not be measured due to limitations of equipment. From the DSC plot, we have found that the Neel temperature in BNFM sample is in the same range after co-doping of Nd and Mn compared to pure BFO \( (T_N = 643 \text{ K}) \), it was reported that cationic substitution of BFO leads to important effect in transitions temperatures \( (T_N, T_C) \) of BFO due to the chemical pressure exerted by dopants on BFO lattice.⁵²,⁶⁵,⁶⁶ We have also observed dielectric and phonon anomalies (described before) in a similar temperature range \(~T_N\) which strongly suggests magneto-dielectric coupling around this temperature.

G. Impedance and modulus spectroscopy

The major observation until now is the appearance of sharp dielectric and phonon anomalies near \( T_N \) which is well supported by endothermic peak in thermal analysis. To determine the physical mechanism responsible for this anomalous effect, we have carried out extensive impedance and modulus spectroscopy over a wide range of temperature and frequency. Figure 6(a) shows the frequency variation of the imaginary part of the impedance \( (Z''\) at different temperatures for a BNFM pellet. With increase of temperature, we can observe: (i) decrease in the magnitude of \( Z'' \) and merging together in the high frequency region, (ii) presence of a peak \( (f_{\text{max}}) \) which shifted towards higher frequency, (iii) peak
The intensity of the $Z''$ peak varies strongly with temperature, indicating Arrhenius-type temperature dependence. The activation energy associated with this relaxation process was determined using Eq. (2)

$$\tau = \tau_0 \exp(E_a/k_B T),$$

where $\tau_0$ is the prefactor, $E_a$ the activation energy for the relaxation process, and $k_B$ the Boltzmann constant. The activation energy associated with this process was 0.41 eV (see inset Figure 6(a)), since only one peak was observed in $Z''$ vs. $f$, this response is mainly dominated by grain contribution. It was reported in oxide ferroelectric thin films that the short range order of oxygen vacancies ($V_O$) play an important role in the dielectric relaxation; however, the ionization of oxygen vacancies known as first ($V'_O + e$) ($E_a < 0.70$ eV) and second ionization ($V''_O + e$) ($E_a \sim 1.4$ eV) will create conducting electrons, which affect the dielectric relaxation. According to the numerical values obtained for $E_a$ of BNFM, we conclude that the first ionization process can be responsible for dielectric relaxation.

The frequency dependent imaginary part of electric modulus $M''$ is shown in Figure 6(b) for various temperatures for BNFM sample. At each temperature only one peak was observed in the frequency window studied with similar features already discussed for $Z''$ vs $f$. The inset of Figure 6(b) shows $\tau$ vs. $1000/T$ plot which followed the Arrhenius behavior (Eq. (2)), and the calculated value 0.39 eV for $E_a$ is in well agreement with value obtained from $Z''$ vs. $f$ plot.

Complex impedance spectroscopy is an important and effective technique to study and analyze the electrical response of dielectric or ionic materials. Figure 6(c) and its inset show the complex impedance plot of BNFM sample at higher temperatures (550 K–650 K) and lower temperatures (400 K–500 K), respectively over a wide range of frequencies (100 Hz–1 MHz). The complex impedance plot is characterized by the presence of semicircle arc whose pattern of evolution differs with increase of temperature; the high frequency semicircle represents the contribution of bulk (grain-G) property of that material, whereas low frequency semicircle represents the contribution of grain boundary (GB). In the temperature range from 550 K to 640 K, two different contributions can be observed at low/high frequency side corresponding to GB/G contributions, respectively. It is important to note that the GB contribution is present only in the $T_N$ region (see green rectangle in Figure 6(c)), not GB contributions was observed below 550 K (see inset of Figure 6(c)) and above 650 K. Ghosh et al. observed an anomaly in real and imaginary parts of the permittivity vs. temperature around $T_N$ for multiferroic Pr(Sr0.1Ca0.9)2Mn2O7. The frequency variation and relaxation process exhibited around $T_N$, can be assigned to the coupling between magnetic and electric order parameters, due to the fluctuation in the coupling dynamics between polar domains and long-range magnetic order. It was also reported that this behavior can be also caused by magnetodielectric effect which is principally due to magnetoresistive response of the multiferroic sample.

It confirms that active conducting (resistive) grain boundaries are responsible for the large magnetic-dielectric response and dielectric anomaly in the vicinity of $T_N$.

Complex electric modulus plot ($M'$ vs. $M''$) of ceramic BNFM is shown in Figure 6(d) at selected temperatures (400 K–650 K). It was found that high temperature $M'$ vs. $M''$ curve can be fit with a single semicircle arc with the center located below the $M'$ axis and indicates that the spectrum of relaxation time is present in the sample but distributed around a mean value. The semicircle observed near $T_N$ corresponding to grain relaxation process. We believe capacitance corresponding to the grain boundary is very small.
compared with grain contribution, only small signature of GB contribution was observed below 650 K in the $T_N$ regions (see the asymmetric semicircular arcs in Figure 6(d)), in agree with complex impedance results. The $M' \times M''$ plot shows change in its shape and size with rise in temperature suggesting a change in the capacitance values of the material as a function of temperature.\textsuperscript{76}

H. Complex conductivity spectroscopy

To study the mechanism of temperature dependent electrical transport in BNFM sample, ac conductivity ($\sigma_{ac}$) vs angular frequency ($\omega$) was plotted in temperature range from 400 K to 650 K (Figure 7(a)). The $\sigma_{ac}$ was calculated by using an empirical dielectric relation

$$\sigma_{ac} = \omega \varepsilon_{r0} \varepsilon_0 \tan \delta,$$

where $\omega$ is angular frequency and $\varepsilon_0$ is vacuum permittivity.\textsuperscript{77-79}

The conductivity plots of BNFM possess following characteristics: (i) at temperatures below 450 K, the conductivity becomes a strong function of frequency and a short dc plateau is observable; (ii) above 450 K, a frequency independent plateau for $\omega < 10^5$ Hz and a frequency dependent conductivity at high frequency regions was obtained for $\omega > 10^5$ Hz; (iii) an enhancement of about three orders of frequency independent conductivity with the increase in temperature (from 400 K to 650 K). The above-mentioned observation in conductivity spectra can be explained on the basis of jump relaxation model. The frequency independent plateau at low frequency for higher temperatures ($>450$ K) is attributed to the long-range translational motion of ions contributing to dc conductivity. The observed frequency independent dc conductivity (at higher temperatures) was explained by Funke\textsuperscript{80} in the jump relaxation model. According to this model, the conductivity at low frequency region is associated with the successful hops to its neighborhood vacant site due to the available long time period; such successive jumps result in a long-range translational motion of ions contributing to dc conductivity. At high frequency ($>10^5$ Hz), two competing relaxation process may be visualized: (i) the jumping ion to jump back to its initial position (correlated forward-backward-forward), i.e.,

\begin{figure}[h]
\centering
\includegraphics[width=\textwidth]{figure6.png}
\caption{Frequency dependence of (a) imaginary part of impedance spectra ($Z''$) and (b) imaginary part of electric modulus ($M''$) at elevated temperatures ($>400$ K). (c) Complex impedance plane plot ($Z'\times Z$) and (d) Complex electric modulus plane plot ($M'\times M$) at different temperatures for BNFM ceramic.}
\end{figure}
unsuccesful hopping and (ii) The neighborhood ions become relaxed with respect to the ion’s position (the ions stay in the new site), i.e., successful hop. The increase in the ratio of successful to unsuccessful hopping results in a more dispersive conductivity at high frequencies. The frequency dependent ac conductivity of BNFM ceramic obeys Jonscher’s power law (Eq. (4))\(^81\) at all temperatures (400 K to 650 K)

\[
\sigma(\omega) = \sigma(0) + A\omega^n, \tag{4}
\]

where \(\sigma(\omega)\) is the total conductivity, \(\sigma(0)\) is the frequency independent conductivity (dc plateau in Figure 7(a)), and the coefficient \(A\) and exponent \(n\) (\(0 < n < 1\)) are temperature and material intrinsic property dependent constants. The term \(A\omega^n\) contains the ac dependence and characterizes all dispersion phenomena (higher frequency region, \(\omega > 10^5\) in Figure 7(a)). A good agreement was found between experimental data (open circles) and fitted values (solid lines) in Figure 7(a). A broad shoulder peak in the low frequency region (100 to 1500 Hz) of ac conductivity was observed in the temperature range from 600 K to 640 K (see green rectangle in Figure 7(a)), this temperature range correspond to \(T_N\) region, in which a clear peak was also observed in \(\varepsilon_r\) vs. \(T\) and heat flow vs. \(T\) plots (Figure 5).

The inset of Figure 7(a) presents the temperature dependent exponent \((n)\) obtained from fitted data. The \(n\) values were found to vary between 0.48 and 0.69. In the temperature range from 570 to 620 K, \(n\) vs. \(T\) shows an unusual variation that is well supported by Raman, dielectric, calorimetry, and complex impedance results. Similar anomaly for \(n\) and \(A\) was observed by Peláz-Barranco et al.\(^82\) around \(T_N\) for ferrimagnetic \(\text{Zn}_{0.44}\text{Mn}_{0.56}\text{Fe}_2\text{O}_4\). These results can indicate the coupling of ferroelectric and magnetic phase and can be associated with a critical behavior in electrical conductivity parameters \((n\) and \(A)\). It was observed that below 570 K and above 620 K the values of \(n\) decrease and increase, respectively. The value of \(n\) defines the motion of charge carriers is either translational or localized. If value of \(n < 1\), the motion is translational, and if value of \(n > 1\), the motion is localized. Different hopping mechanisms have been reported by various researchers and these mechanisms predicted different temperature and frequency dependence on exponent \(n\). In case of small polaron hopping, \(n\) increases with temperature, while for a large polaron hopping, \(n\) decreases with increasing temperature.\(^83\) As shown in inset of Figure 7(a), the numerical values of \(n\) obtained are \(< 1\) and are found to decrease below 570 K and increase above 620 K, hence we conclude that the conduction arises mainly due to the short-range order translation hopping assisted by both large polaron \((T < 570\text{ K})\) and small polaron \((T > 620\text{ K})\) hopping mechanisms.

Figure 7(b) shows the variation of ac conductivity with inverse of temperature at different frequencies. The activation energy for different frequencies was calculated using Arrhenius relation from the slope of the solid lines in Figure 7(b).

\[
\sigma_{AC} = \sigma_0 \exp\left(\frac{E_a}{k_BT}\right), \tag{5}
\]

where \(\sigma_0\) is the prefactor, \(E_a\) the activation energy for charge conduction. From Figure 7(b) it was observed that the \(\sigma_{AC}\) is both frequency and temperature dependent in all temperature regions labeled as I, II, and III. However, at low temperatures (region I) a less temperature dependence was observed as compared to the regions II and III. On the other hand, a higher temperature dependence was found in regions II and III in comparison with region I. As it was explained before, the dispersion of \(\sigma_{AC}\), that is, the ratio of successful to unsuccessful hopping of the charge carriers, is highly dependent of frequency and temperature. We found considerable increase of ac conductivity around Neél temperature (see green rectangle in Figure 7(b)), which may be attributed to the coupling between moving charge carriers and magnetic moments around Neél temperature.\(^84\) The activation energies calculated from ac conductivity spectra (Figure 7(b)) in different temperature regions (I, II, III) at selected frequencies are given in Table IV. It was found that the activation energies determined in regions II and III are in the same range as those calculated from \(\varepsilon''\) vs. \(f\) (0.42 eV) and \(M''\) vs. \(f\) (0.39 eV) plots for the same temperature interval.

![Figure 7](image-url)
Table IV. Activation energies ($E_a$) calculated from ln$\sigma$ vs 1000/T for BNFM ceramic.

<table>
<thead>
<tr>
<th>Region</th>
<th>Temperature (K)</th>
<th>$E_a$ (eV)</th>
</tr>
</thead>
<tbody>
<tr>
<td>I</td>
<td>300-400</td>
<td>0.20</td>
</tr>
<tr>
<td>II</td>
<td>410-500</td>
<td>0.33</td>
</tr>
<tr>
<td>III</td>
<td>510-650</td>
<td>0.49</td>
</tr>
</tbody>
</table>

(400 K–650 K). The conductivities in regions II and III were attributed to the contributions of short and long range movement of oxygen vacancies, respectively.\(^8^5\)

I. Magnetic properties

Figure 8 shows the equilibrium magnetization (M-H) loops of BNFM ceramics with a magnetic field of up to 7 T (70 kOe) at different temperatures. At room temperature, M-H loops indicate weak ferromagnetic nature of the BNFM sample with remanent magnetization 0.034 emu/g and coercivity 0.415 T, respectively. A similar slow increase in magnetization was observed in Bi$_{1-x}$Nd$_x$FeO$_3$ and Bi$_{0.9-x}$La$_{0.1}$Eu$_x$FeO$_3$ for low values of x (x ≤ 0.1)\(^8^5\). On the other hand, it was found that the BiFe$_{1-x}$Mn$_x$O$_3$ (x ≤ 0.3) shows an increase in magnetization with increase in Mn content but antiferromagnetic nature was observed in all samples.\(^8^7\) The improvement in magnetic properties in the BNFM ceramic sample could be due to collapse of the spin cycloid structure. This may be caused by the Nd and Mn doping in the A and B sites of the BFO due to structural distortion such as changes in the bond length and bond angles.\(^8^8\). The weak magnetization with larger coercive field and small remanent magnetization ($M_r$) observed in the BNFM samples can be due to the presence of iron oxides impurities.\(^8^8\) However, M-H loops were not saturated even if at a high applied magnetic field of 7 T indicating the slow transformation of G-type antiferromagnetic behavior of BFO into a weak ferromagnetic BNFM material.

An increase was observed in so-called saturation magnetization values from 0.59 to 0.97 emu/g when the temperature decreased from 300 K to 15 K at 7 T. However, simultaneously a decrease in $M_r$ value from 0.034 to 0.029 emu/g was observed (see the inset of Figure 8). This increase in magnetization and decrease in $M_r$ can be due to competition between weak ferromagnetism observed when Bi is substituted by Nd and an increase in the magnetization with antiferromagnetic behavior when Fe is replaced by Mn, as was discussed above.

J. Magnetoelectric coupling

For further understanding the coupling between electric and magnetic order parameters, the magnetoelectric effects in Nd and Mn co-doped BFO were studied. The magnetoelectric coefficient (z) was measured in in-plane mode for H and $\partial H$ parallel to each other and to the sample plane and perpendicular to $\partial E$ at room temperature. Figure 9 shows the H dependence of the transverse magnetoelectric coefficient ($z_{E,31}$) at room temperature carried out at 1 kHz, an enlarged view of

same plot within small applied magnetic field is presented in the inset of Figure 9. The $z_{E,31}$ increases slowly as field increases from zero, and exhibits a broad maxima around H = 600 Oe with a value of 0.124 mV/cm Oe, and subsequently decreases sharply as H increases. After a certain value of magnetic fields, the magnetostriction gets saturated producing a nearly constant electric field, thereby decreasing magnetoelectric coefficient (z) with further increasing the magnetic field.\(^9^0\) Arya et al.\(^4^2\) have studied magnetoelectric effect in BFO, Bi$_{0.9}$Bi$_{0.1}$FeO$_3$, (BIFO), BiFe$_{0.95}$Ti$_{0.05}$O$_3$ (BFTO), and Bi$_{0.9}$Bi$_{0.1}$Fe$_{0.95}$Ti$_{0.05}$O$_3$ (BFTO) and obtained magnetoelectric coefficient ~0.32, 3.12, 3.45, and 4.8 mV/cmOe, respectively. Kowal et al.\(^9^1\) have investigated magnetoelectric properties in (BiFeO$_3$)$_{1-x}$(BaTiO$_3$)$_{1-x}$ (x = 0.9) solid solutions and observed magnetoelectric coefficient ($z_{E,31}$) around 0.380 mV Oe$^{-1}$ cm$^{-1}$. Naik et al.\(^9^2\) have reported magnetoelectric effect in pure and cation doped BFO and observed magnetoelectric coefficient ($z_{E,31}$) ~0.285 mV Oe$^{-1}$ cm$^{-1}$ for pure BFO, ~0.377 mV Oe$^{-1}$ cm$^{-1}$ for Sr$_{0.3}$, doped BFO, ~0.648 mV Oe$^{-1}$ cm$^{-1}$ for Ba$_{0.3}$ doped BFO and ~2.31 mV Oe$^{-1}$ cm$^{-1}$ for Sr$_{0.15}$Ba$_{0.15}$ doped BFO ceramics, respectively. The numerical value of z achieved in the present study is comparable with the corresponding figures obtained earlier for pure BFO and doped BFO.\(^9^2\). Magnetoelectric (ME) coupling in single-phase ceramics originates due to spin-orbit coupling along the preferential axis of spins; however, significant change in the strength of anisotropy and local symmetry due to external electric/magnetic field decides the magnitude and direction of magnetoelectric coefficient as a function of electric/magnetic fields. Restricting ourselves to the linear coupling term, then, $E_{ME(H)} = zH$ where $E$ is applied electric field, $H$ is applied magnetic field and $z$ is ME coefficient. Ideally $z$ should increase initially, then saturate, and later decrease with increase in applied fields. The behavior of z may be significantly different due to distribution of grains, grain boundaries and their orientation after poling.\(^9^0\) The field dependency of transverse magnetoelectric coefficient ($z_{E,31}$) can be attributed to the non-linear response of magneto-stress coupling in sample.\(^9^3\) The hysteresis behavior of $z_{E,31}$ is almost symmetric
FIG. 9. Magneto-electric voltage coefficient ($\varepsilon_{31}$) as a function of the bias magnetic field in transverse mode for BNFM ceramic sample at room temperature. Inset shows the closer view of the respective data.

IV. CONCLUSIONS

In summary, we have observed a large dielectric anomaly, phonon frequency anomaly, and significant change in thermal energy in the vicinity of $T_N$. Some earlier researchers also observed similar behavior near the magnetic phase transition temperature in BFO and other magnetic materials. It is well known that conducting BFO and small co-doped BFO grain boundaries and domain walls have magnetic rich phase which is more perturbed near $T_N$. In this article, we confirmed that the active grain boundary contributions are responsible for large dielectric anomaly and magneto-dielectric behavior in the vicinity of $T_N$. Small cationic substitutions with Nd and Mn co-doped BFO show sharp endothermic peak around 620 K with broad exothermic peak near 638–643 K (relatively similar to $T_N$ of BFO), whereas the first transition is due to the grain boundary induced large dielectric anomaly while the latter one as Néel temperature. BNFM illustrates high magneto-electric coupling coefficient (0.124 mV/cm Oe) at zero bias magnetic field, which reduces with increase in the applied dc magnetic field.

ACKNOWLEDGMENTS

This work was supported by the DOE Grant DE-FG02-08ER46526 and NSF (Fellowship EPS 10002410). N. Ortega acknowledges financial support from the NSF-RII Grant R10701525 and Dr. Ashok Kumar was supported by DOD Grant W911NF-11-1-0204. The authors thank Josue Ortiz Morales (MCC) for his help in the XPS measurements.
